

NOT RECOMMENDED FOR NEW DESIGN **USE DMN3025LSS**



DMN3052LSS

SINGLE N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	30mΩ @ V _{GS} = 10V	7.1A
30V	40mΩ @ V _{GS} = 4.5V	6.2A
	63mΩ @ V _{GS} = 2.5V	4.9A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- **Power Management Functions**
- DC-DC Converters

Features and Benefits

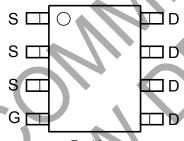
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

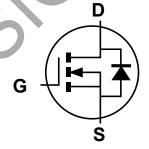
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.074 grams (approximate)



TOP VIEW



Top View Internal Schematic



Equivalent circuit

Ordering Information (Note 4)

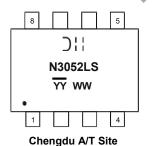
Part Number	Case	Packaging
DMN3052LSS-13	SO-8	2500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"
- . Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





);; = Manufacturer's Marking N3052LS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 13 = 2013) WW = Week (01 - 53)

YY = Date Code Marking for SAT (Shanghai Assembly/ Test site) YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)



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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±12	V
Drain Current (Note 5)	Steady State	T _A = +25°C T _A = +70°C	I _D	7.1 5.7	Α
Pulsed Drain Current (Note 6)			I _{DM}	28	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P_{D}	2.5	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	50	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

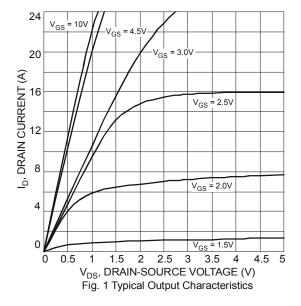
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

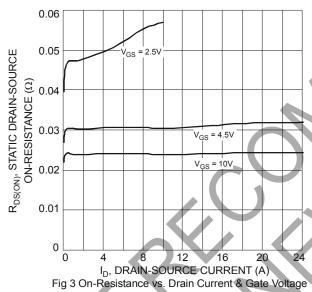
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV_{DSS}	30	1/2 4		V	$V_{GS} = 0V$, $I_D = 250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	4	+-	1	μA	$V_{DS} = 30V$, $V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	A	7	±80 ±800	SWEETIA III	$V_{GS} = \pm 12V, V_{DS} = 0V$ $V_{GS} = \pm 19V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)	ON CHARACTERISTICS (Note 7)					
Gate Threshold Voltage	V _{GS(th)}	0.62	0.9	1.2	>	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
Static Drain-Source On-Resistance	RDS (ON)		24 30 50	30 40 63	97	$V_{GS} = 10V$, $I_D = 7.1A$ $V_{GS} = 4.5V$, $I_D = 6.4A$ $V_{GS} = 2.5V$, $I_D = 5.0A$
Forward Transconductance	g _{fs}	_ `	10		S	$V_{DS} = 5V, I_D = 5.1A$
Diode Forward Voltage (Note 7)	V_{SD}	-	0.78	1.16	V	$V_{GS} = 0V, I_S = 2.1A$
DYNAMIC CHARACTERISTICS						
Input Capacitance	C _{iss}		555		pF	51/1/
Output Capacitance	Coss		109		pF	V _{DS} = 5V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	/	82	_	pF	

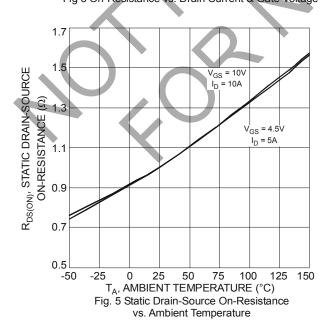
Notes:

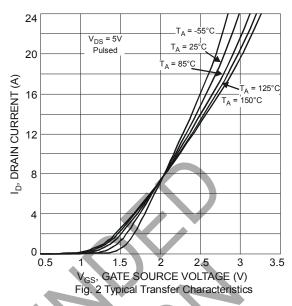
- 5. Device mounted on 2 oz copper pad layout with $R_{\theta JA} = 50^{\circ}$ C/W.
- Pulse width ≤10µS, Duty Cycle ≤1%. Short duration pulse test used to minimize self-heating effect.

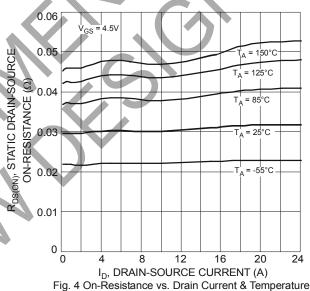




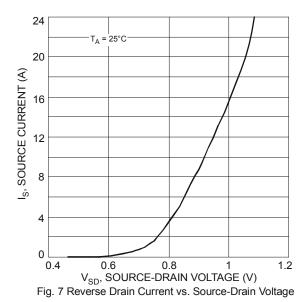


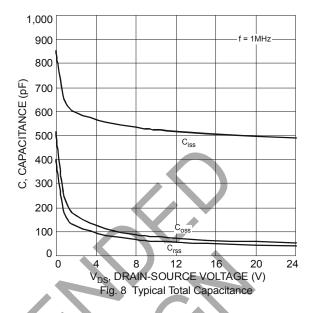


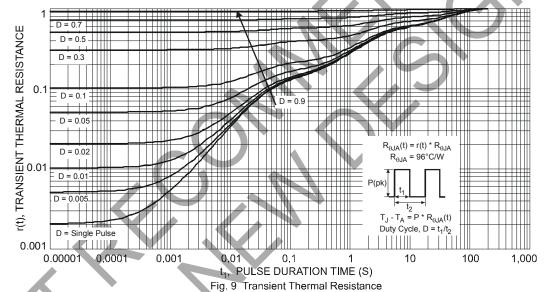






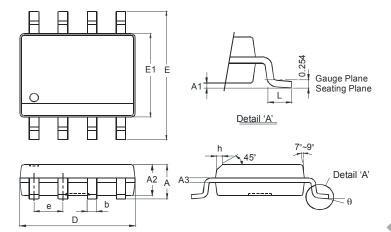






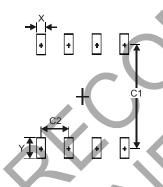


Package Outline Dimensions



	SO-8		
Dim	Min	Max	
Α	-	1.75	
A1	0.10	0.20	
A2	1.30	1.50	
A3	0.15	0.25	
b	0.3	0.5	
D	4.85	4.95	
Е	5.90	6.10	
E1	3.85	3.95	
Ф	1.27 Typ		
h	- 0	0.35	
L	0.62	0.82	
θ	0°	8°	
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.60
Υ	1.55
C1	5.4
C2	1 27



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